

Ionic Ir(III) Complex-Interfacial Layer for Efficient Carrier Collection via Induced Electric Dipole

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Synthesis and characterization, XRD, GI-WAXD, device performance, IPCE, stability test and XPS depth profile, Scheme 1-4, Fig. S1-19, and Table S1-4.

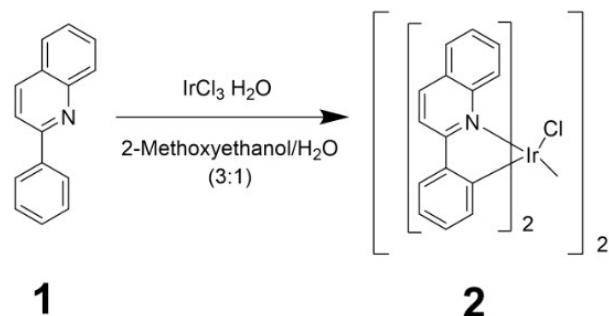
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1. Synthesis and characterization

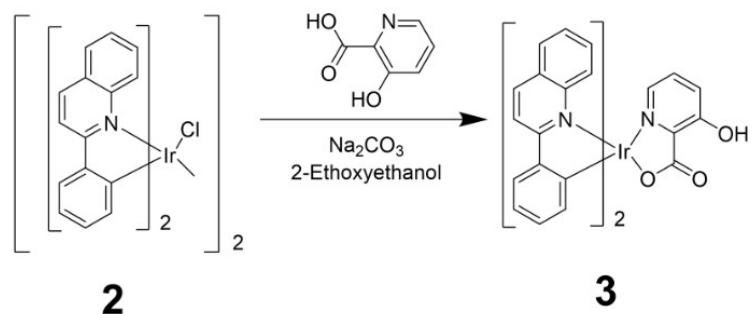
In this study, 2-phenylquinoline (2pq, 1) was chosen as the main ligand in the iridium complexes because iridium (III) complex with 2pq ligand exhibited high absorption coefficient in UV region in previous studies.

Scheme 1



Compound 2: A mixture of $\text{IrCl}_3 \cdot \text{H}_2\text{O}$ (500 mg, 1.68 mmol) and 2-phenylquinoline (700 mg, 3.41 mmol) was refluxed for 24 h in a 3:1 mixture of 2-methoxyethanol and water. After cooling to room temperature, more water added to precipitate the product. The resulting mixture was subsequently filtered through a Buchner funnel and then washed with hexane and ethyl ether several times to yield the crude product (700 mg, 62.7% yield).

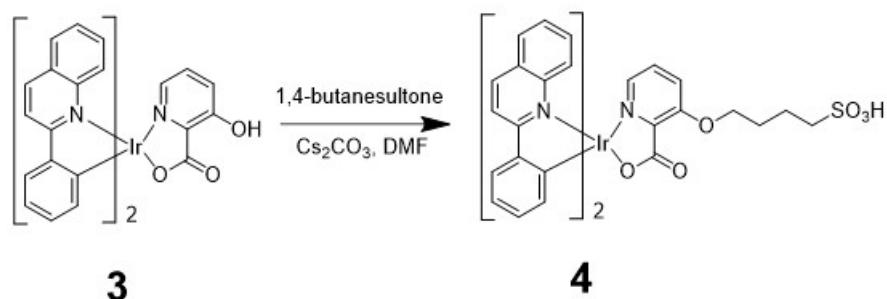
Scheme 2



Compound 3: A mixture of compound 2 (500 mg, 0.393 mmol), 3-hydroxypicolinic acid (164 mg, 1.68 mmol) and Na_2CO_3 (417 mg, 3.93 mmol) was refluxed in an inert (N_2) atmosphere for 10-12 h in 2-ethoxyethanol. After cooling to room temperature, the solvent was evaporated in high vacuum and dissolved in methylene chloride. The organic phase was washed with water and dried over MgSO_4 . The solvent was evaporated to give the crude product, which was applied to column chromatography on silica gel, followed by eluting with methylene chloride and methyl alcohol (10:1, v/v) to provide the desired product (420 mg, 72.3% yield).

^1H NMR (400 MHz, DMSO): δ (ppm) 13.45 (s, 1H), 8.68 (d, 1H), 8.24 (d, 1H), 8.22 (d, 1H), 8.14 (m, 2H), 7.98 (dd, 1H), 7.87 (dd, 1H), 7.77 (m, 2H), 7.58 (m, 1H), 7.50 (m, 2H), 7.39 (m, 2H), 7.15 (m, 2H), 7.13 (m, 1H), 7.01 (m, 1H), 6.98 (m, 1H), 6.89 (m, 1H), 6.80 (m, 1H), 6.69 (m, 1H), 6.31 (dd, 1H).

Scheme 3



Compound 4: A mixture of compound 3 (500 mg, 0.67 mmol), Cs₂CO₃ (440 mg, 1.35 mmol) and 1,4-butanesultone (644 mg, 4.73 mmol) in DMF was stirred at room temperature for 24 h. The solvent was evaporated in vacuum and dissolved in methylene chloride. The organic phase was washed with water, brine and dried over MgSO₄. The solvent was evaporated to give the crude product, which was applied to column chromatography on silica gel, eluting with methylene chloride and methyl alcohol (10:1, v/v) to provide the desired product (200 mg, 33% yield), whose spectroscopic data were identical with the reported.²

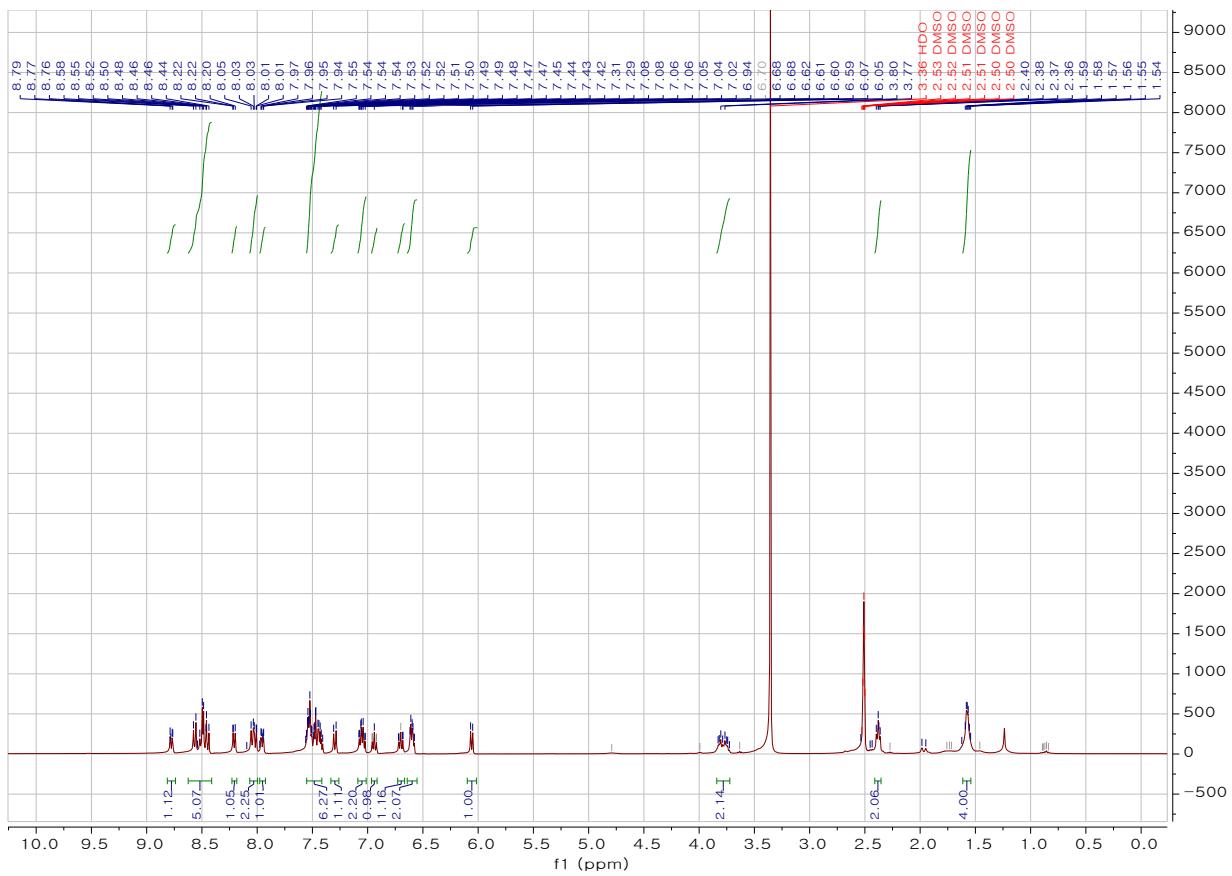


Fig. S1. ^1H NMR of Product 4 in DMSO

^1H NMR (400 MHz, DMSO): δ (ppm) 8.80 (d, 1H), 8.52 (m, 5H), 8.22 (d, 1H), 8.03 (t, 2H), 7.96 (d, 1H), 7.49 (m, 6H), 7.30 (d, 1H), 7.05 (q, 2H), 6.95 (t, 1H), 6.70 (t, 1H), 6.60 (m, 2H), 6.07 (d, 1H), 3.80 (m, 2H), 2.38 (t, 2H), 1.56 (m, 4H).

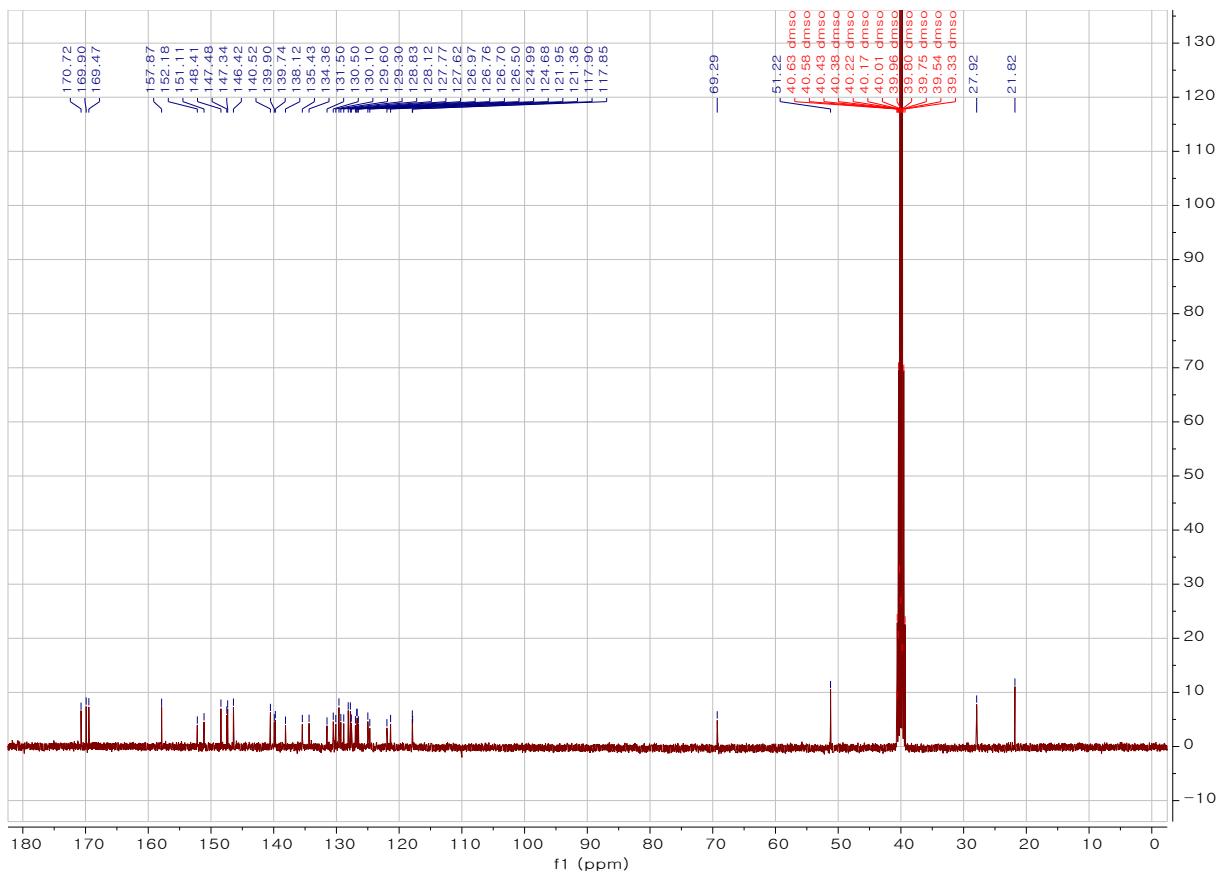
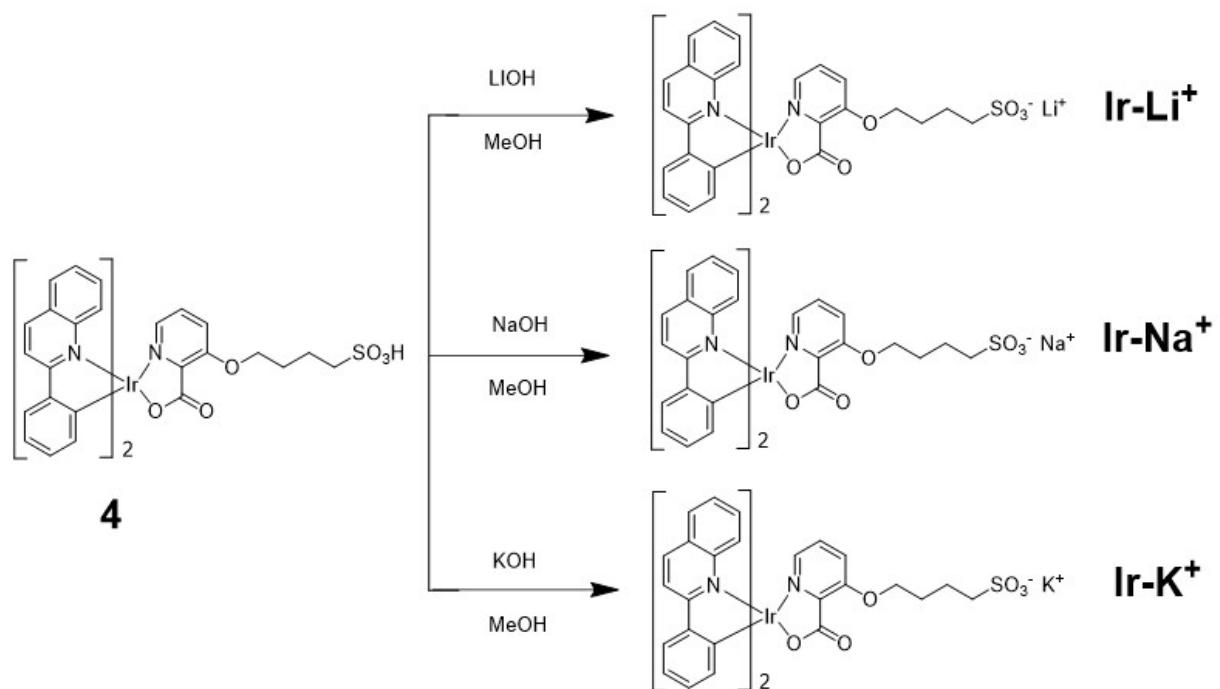


Fig. S2. ^{13}C NMR of Product 4 in DMSO

^{13}C NMR (125 MHz, DMSO): 170.72, 169.90, 169.47, 157.87, 152.18, 151.11, 148.41, 147.48, 147.34, 146.42, 140.52, 139.90, 139.74, 138.12, 136.43, 134.36, 131.50, 130.50, 130.10, 129.60, 129.30, 129.30, 128.83, 128.12, 127.77, 127.63, 126.97, 126.76, 126.70, 126.50, 124.99, 124.68, 121.95, 121.36, 117.90, 117.85, 69.29, 51.22, 27.92, 21.82.

Scheme 4



Ir-Li⁺, Ir-Na⁺, and Ir-K⁺: A mixture of compound 4 (200 mg, 0.11 mmol) and LiOH or NaOH or KOH (10 mg, 0.26 mmol) in methyl alcohol was stirred for 24 h at room temperature. The solvent was evaporated to give the orange-red solid, which was recrystallized in dichloromethane and hexane (180 mg, 88% yield).

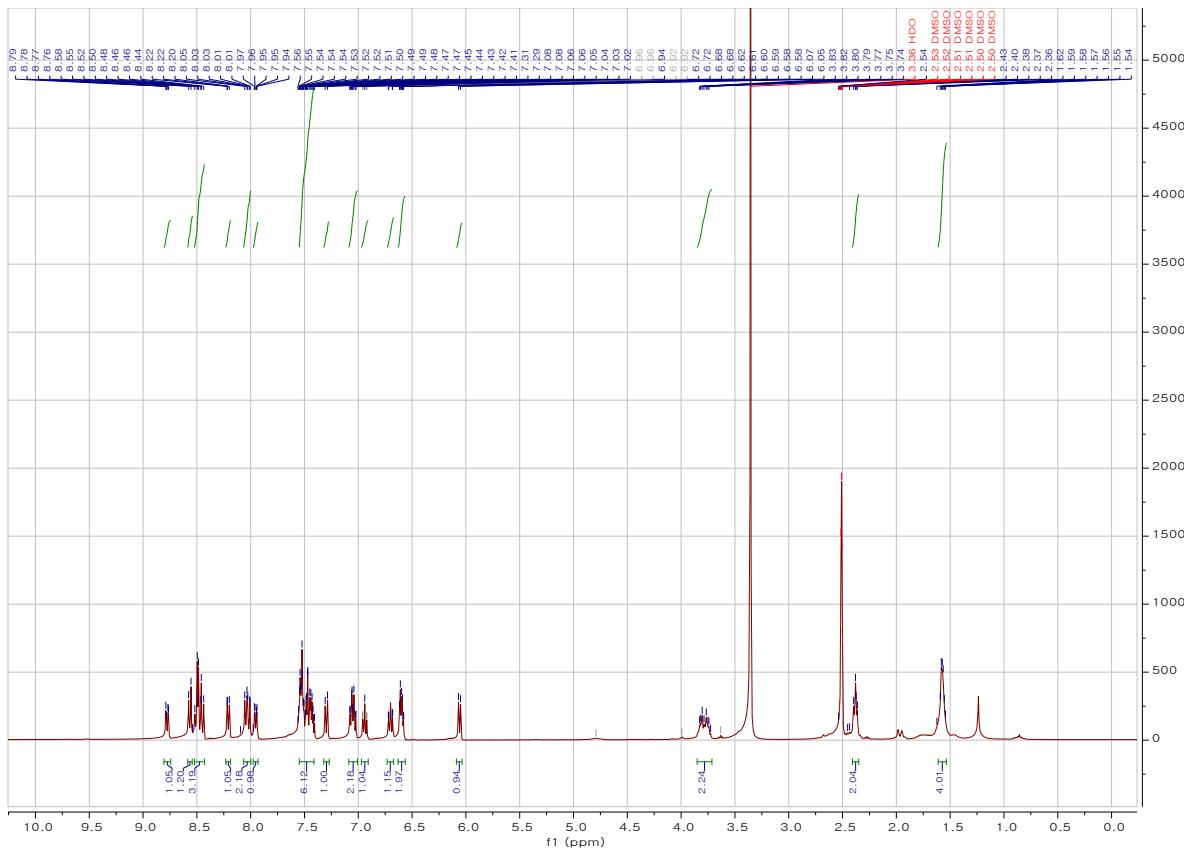


Fig. S3. ^1H NMR of Ir-Li $^+$ in DMSO.

^1H NMR (400 MHz, DMSO): δ (ppm) 8.78 (d, 1H), 8.55 (d, 1H), 8.48 (q, 3H), 8.22 (d, 1H), 8.03 (t, 2H), 7.96 (d, 1H), 7.48 (m, 6H), 7.30 (d, 1H), 7.05 (q, 2H), 6.94 (t, 1H), 6.70 (t, 1H), 6.60 (m, 2H), 6.07 (d, 1H), 3.78 (m, 2H), 2.38 (t, 2H), 1.57 (m, 4H).

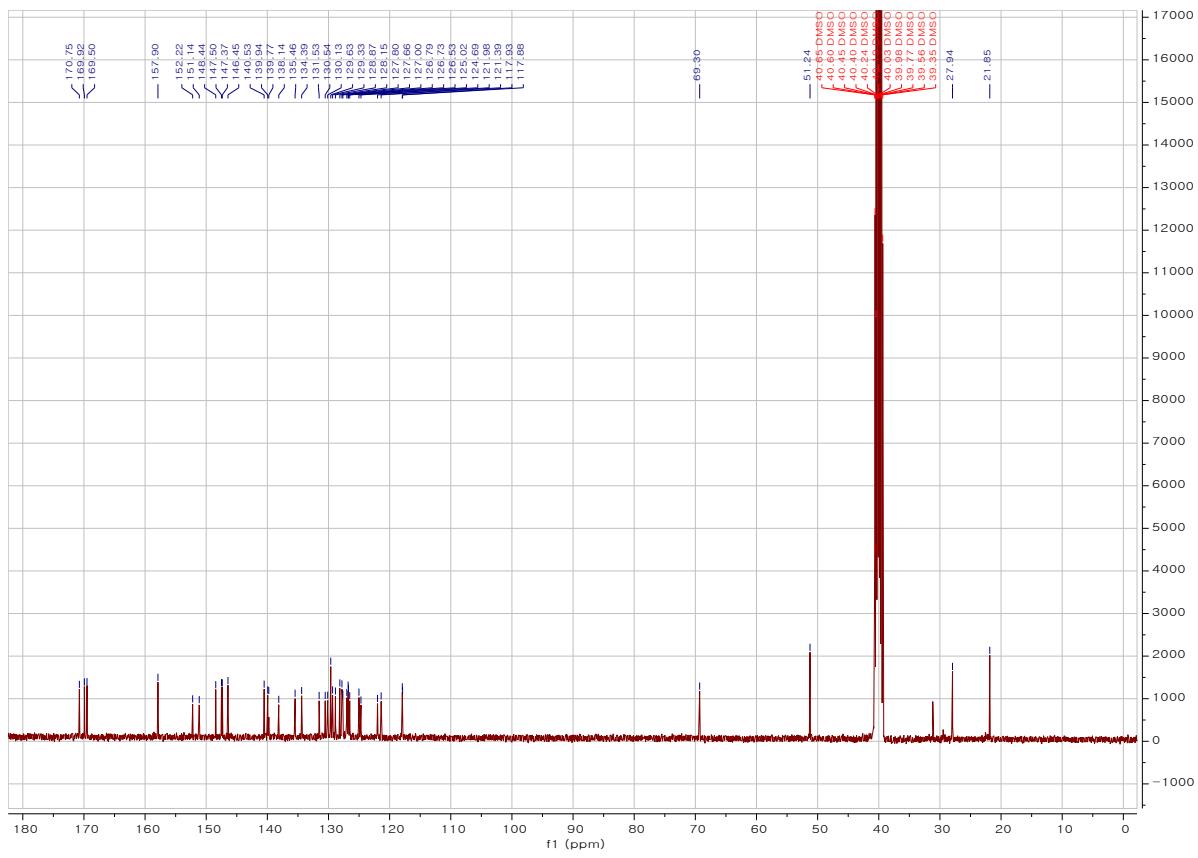


Fig. S4. ^{13}C NMR of Ir-Li $^+$ in DMSO.

¹³C NMR (125 MHz, DMSO): δ (ppm) 170.75, 169.92, 169.50, 157.90, 152.22, 151.14, 148.44, 147.50, 147.37, 146.45, 140.53, 139.94, 139.77, 138.14, 135.46, 134.39, 131.53, 130.54, 130.13, 129.63, 128.87, 128.15, 127.80, 127.66, 127.00, 126.79, 126.73, 126.53, 125.02, 124.69, 121.98, 121.39, 117.93, 117.88, 69.30, 51.24, 27.94, 21.85.

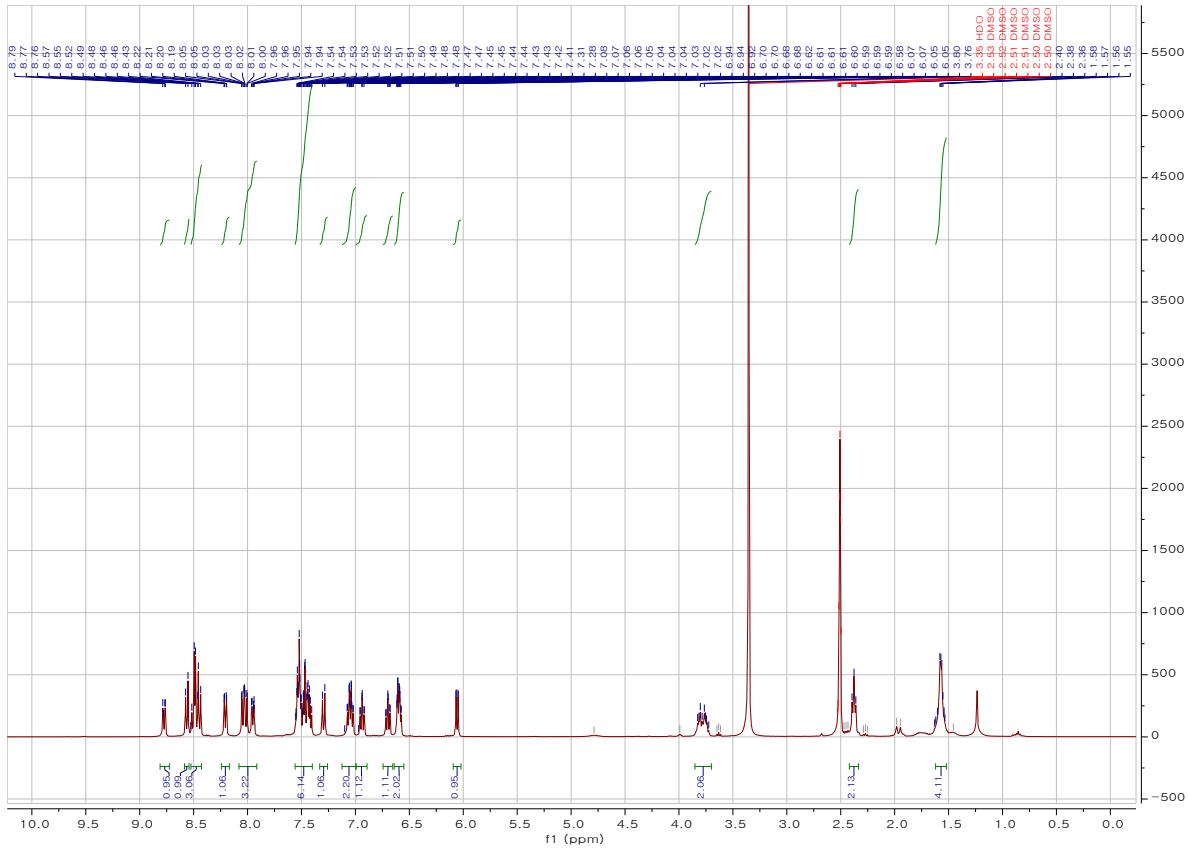


Fig. S5. ^1H NMR of Ir-Na $^+$ in DMSO.

¹H NMR (400 MHz, DMSO): δ (ppm) 8.78 (d, 1H), 8.55 (d, 1H), 8.48 (q, 3H), 8.22 (d, 1H), 8.03 (t, 2H), 7.96 (d, 1H), 7.48 (m, 6H), 7.30 (d, 1H), 7.05 (q, 2H), 6.94 (t, 1H), 6.70 (t, 1H), 6.60 (m, 2H), 6.07 (d, 1H), 3.78 (m, 2H), 2.38 (t, 2H), 1.57 (m, 4H).

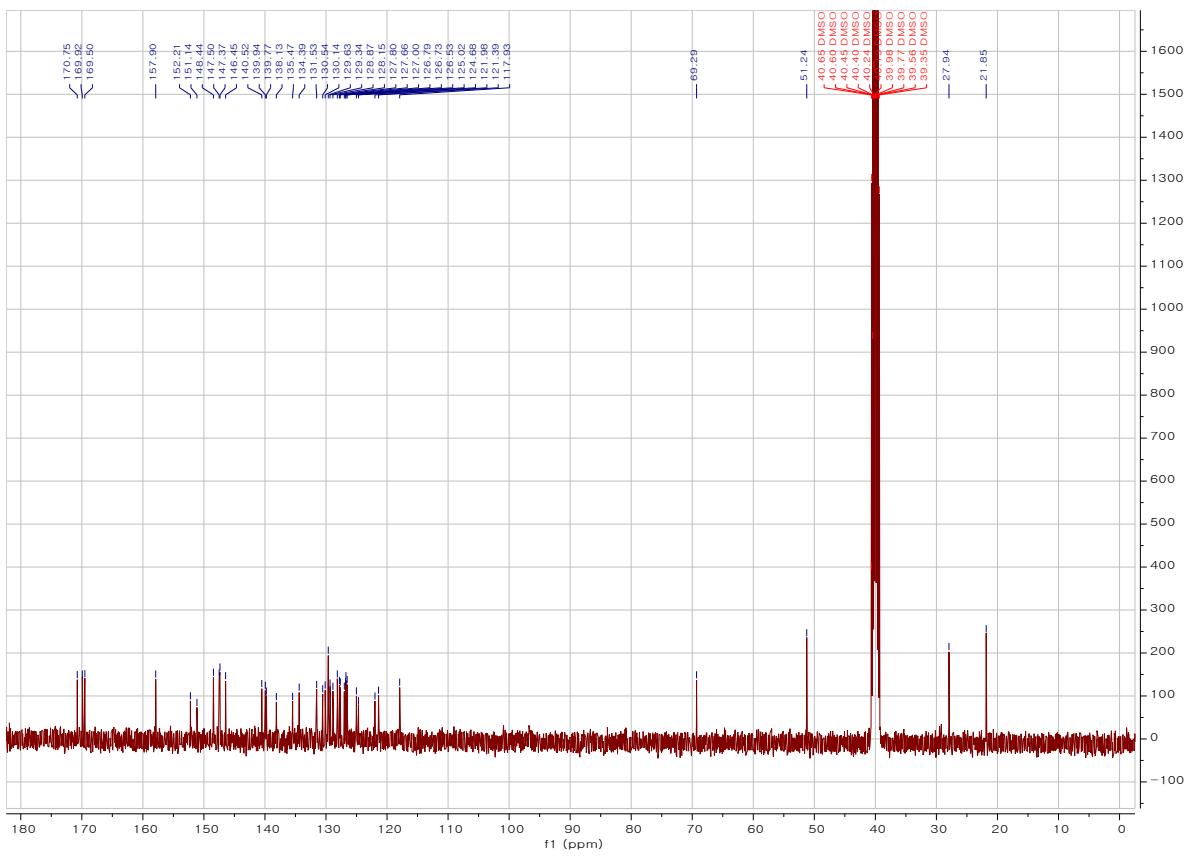


Fig. S6. ^{13}C NMR of Ir- Na^+ in DMSO.

^{13}C NMR (125 MHz, DMSO): δ (ppm) 170.75, 169.92, 169.50, 157.90, 152.21, 151.14, 148.44, 147.50, 147.37, 146.45, 140.52, 139.94, 139.77, 138.13, 135.47, 134.39, 131.53, 130.54, 130.14, 129.63, 129.34, 128.87, 128.15, 127.80, 127.66, 127.00, 126.79, 126.73, 126.53, 125.02, 124.68, 121.98, 121.39, 117.93, 69.29, 51.24, 27.94, 21.85.

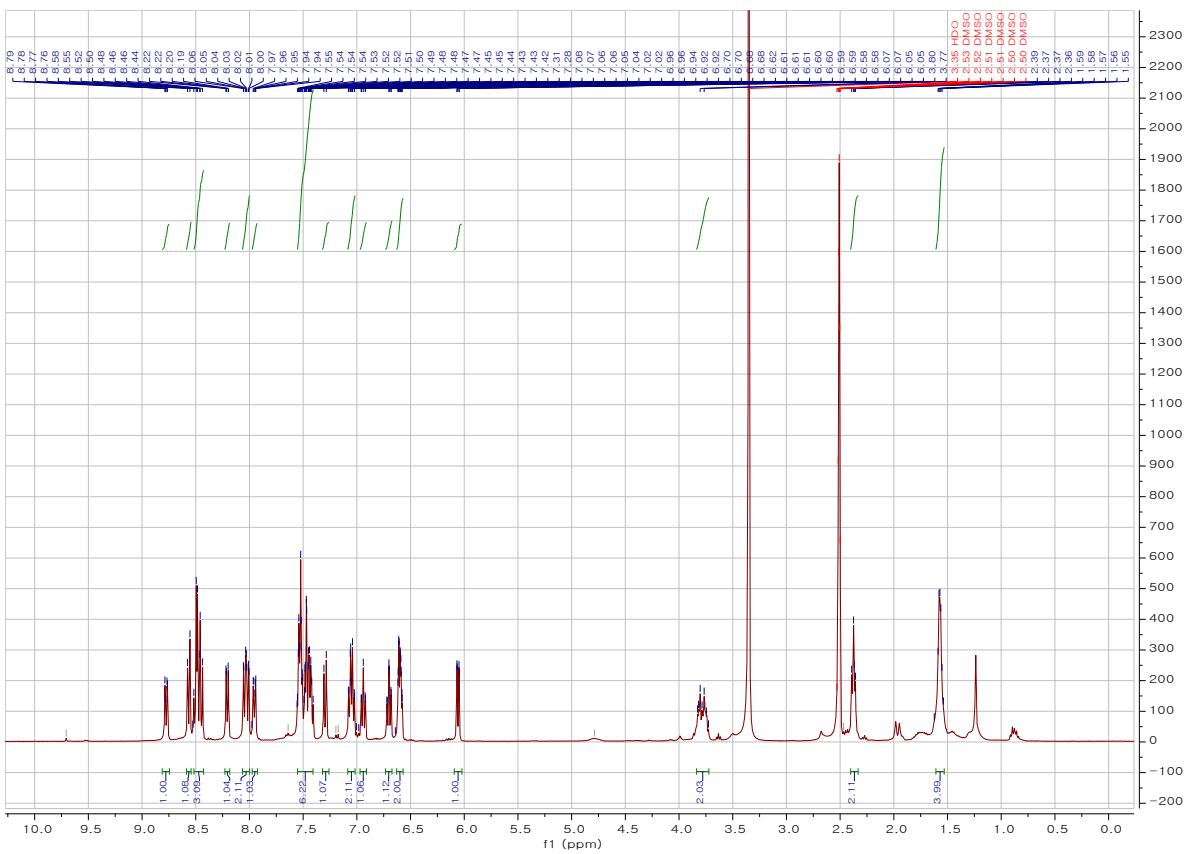


Fig. S7. ^1H NMR of Ir-K $^+$ in DMSO.

^1H NMR (400 MHz, DMSO): δ (ppm) 8.78 (d, 1H), 8.55 (d, 1H), 8.48 (q, 3H), 8.22 (d, 1H), 8.03 (t, 2H), 7.96 (d, 1H), 7.48 (m, 6H), 7.30 (d, 1H), 7.05 (q, 2H), 6.94 (t, 1H), 6.70 (t, 1H), 6.60 (m, 2H), 6.07 (d, 1H), 3.78 (m, 2H), 2.38 (t, 2H), 1.57 (m, 4H).

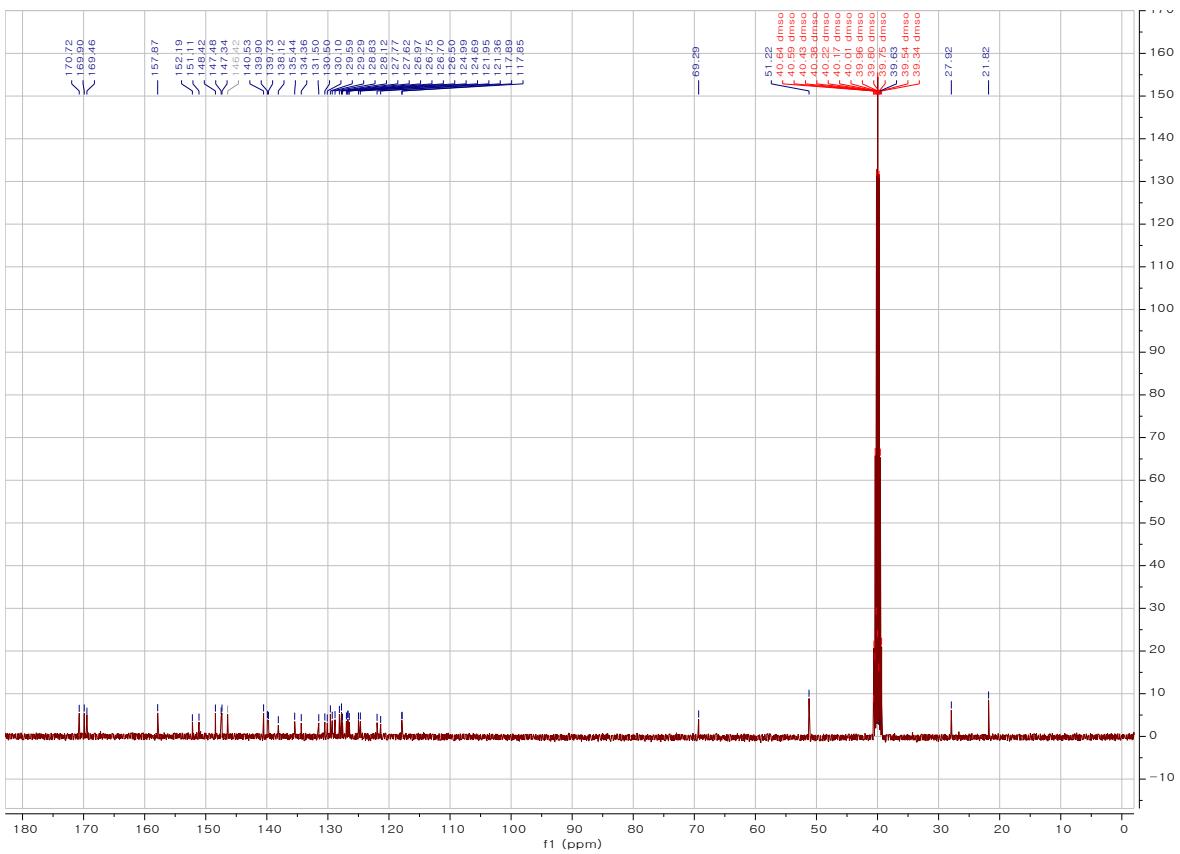


Fig. S8. ^{13}C NMR of Ir- K^+ in DMSO.

^{13}C NMR (125 MHz, DMSO): 170.72, 169.90, 169.47, 157.87, 152.18, 151.11, 148.41, 147.48, 147.34, 146.42, 140.52, 139.90, 139.74, 138.12, 136.43, 134.36, 131.50, 130.50, 130.10, 129.60, 129.30, 129.30, 128.83, 128.12, 127.77, 127.63, 126.97, 126.76, 126.70, 126.50, 124.99, 124.68, 121.95, 121.36, 117.90, 117.85, 69.29, 51.22, 27.92, 21.82.

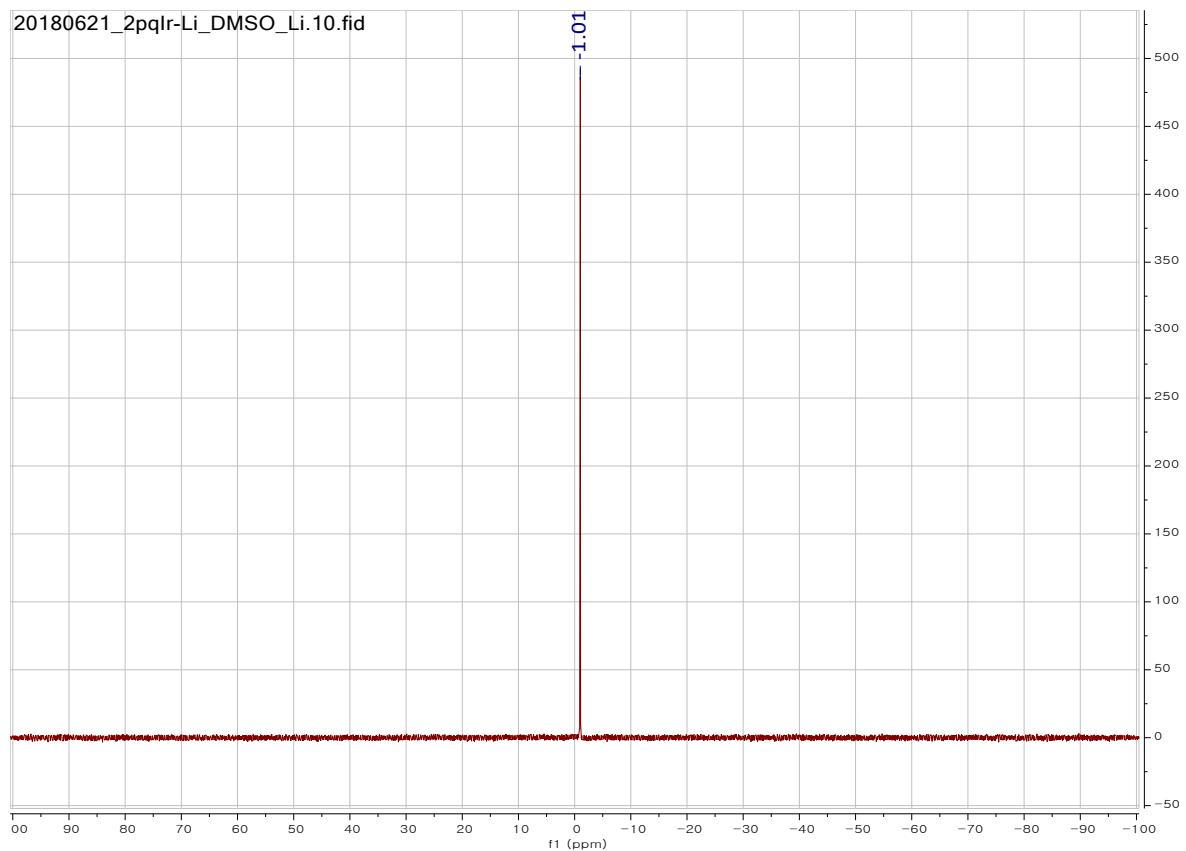


Fig. S9. ⁷Li-NMR spectrum of Ir-Li⁺.

⁷Li-NMR spectrum of Ir-Li⁺ show peak at -1.01 ppm, which correspond to Li salts.

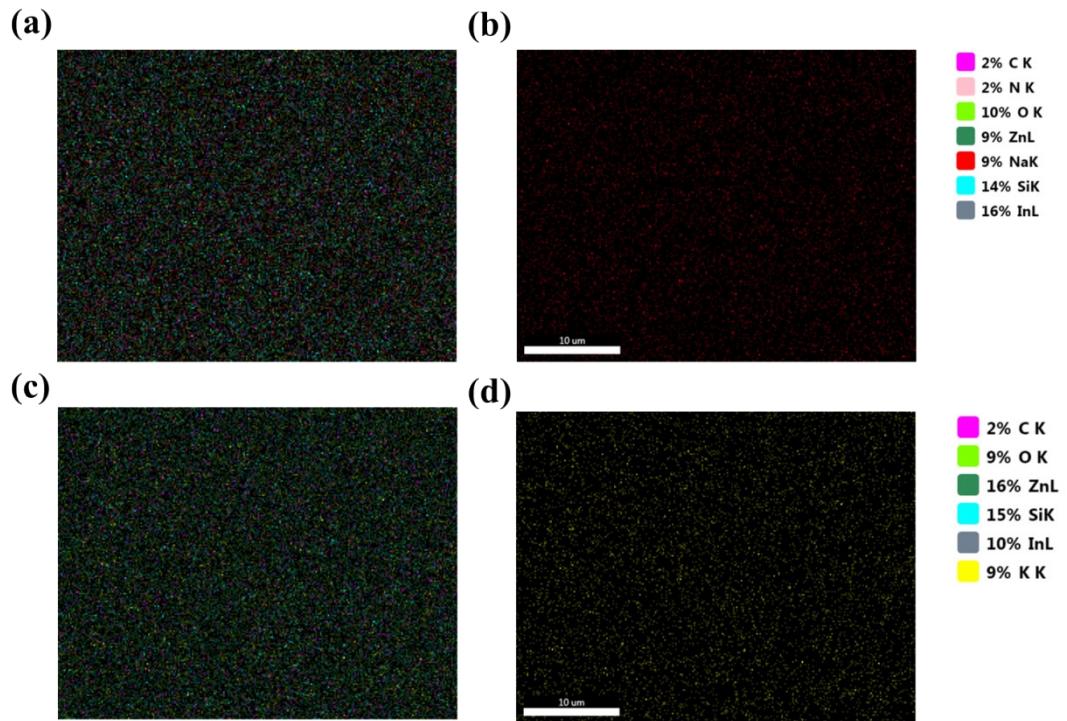


Fig. S10. EDXS mapping images for ITO/ZnO/Ir-Na⁺ films for (a) all elements and (b) Na.

EDXS mapping images for ITO/ZnO/Ir-K⁺ films for (c) all elements and (d) K.

EDXS was proceeded to confirm the ions change in sulfonyl group for Na and K in films, structure of ITO/ZnO/Ir-Na⁺ or Ir-K⁺. Silicon (Si), Indium (In), and Zinc (Zn) peaks are coming from the other layers (Glass, ITO, and ZnO). We found that other cations (Cs, K, and Li) are not detected in films with Ir-Na⁺ through EDXS measurement (Also, Na ion are not detected in films with Ir-K⁺). We also analyze the ITO/ZnO/Ir-Li⁺ films by EDXS measurement, but Li ions are not detected because of instrumental limitation.

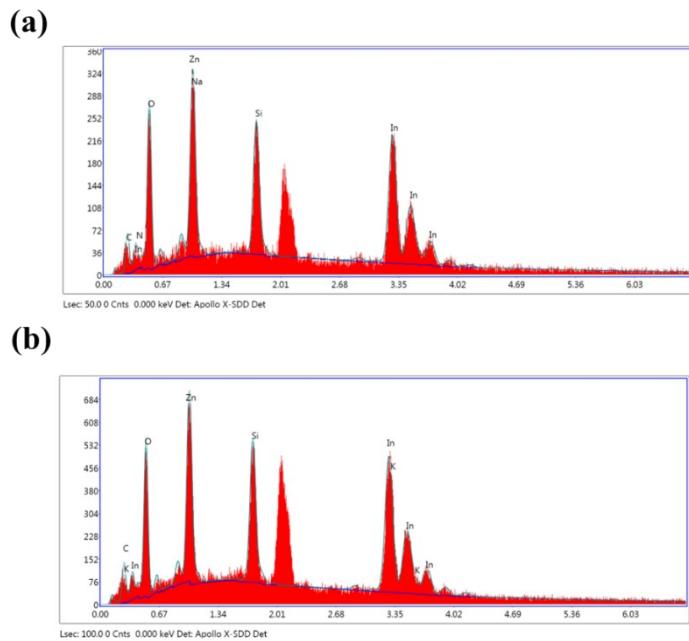


Fig. S11. EDXS data for (a) ITO/ZnO/Ir- Na^+ film and (b) ITO/ZnO/Ir- K^+ film.

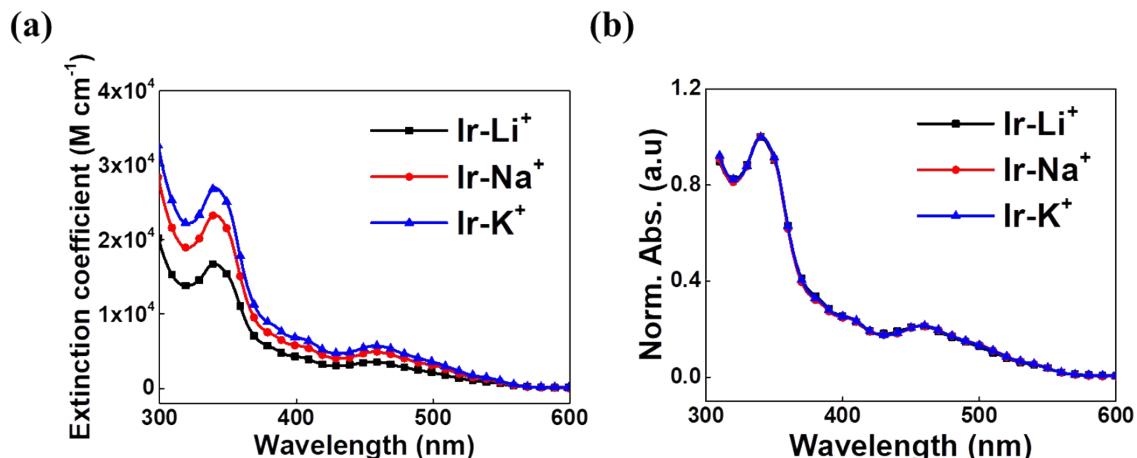


Fig. S12. (a) Extinction coefficient of Ir- Li^+ , Ir- Na^+ , and Ir- K^+ 0.02 mM solution in 2-MeTHF. (b) Normalized absorbance of Ir- Li^+ , Ir- Na^+ , and Ir- K^+ 0.02 mM solution in 2-MeTHF.

2. X-ray diffraction (XRD) analysis

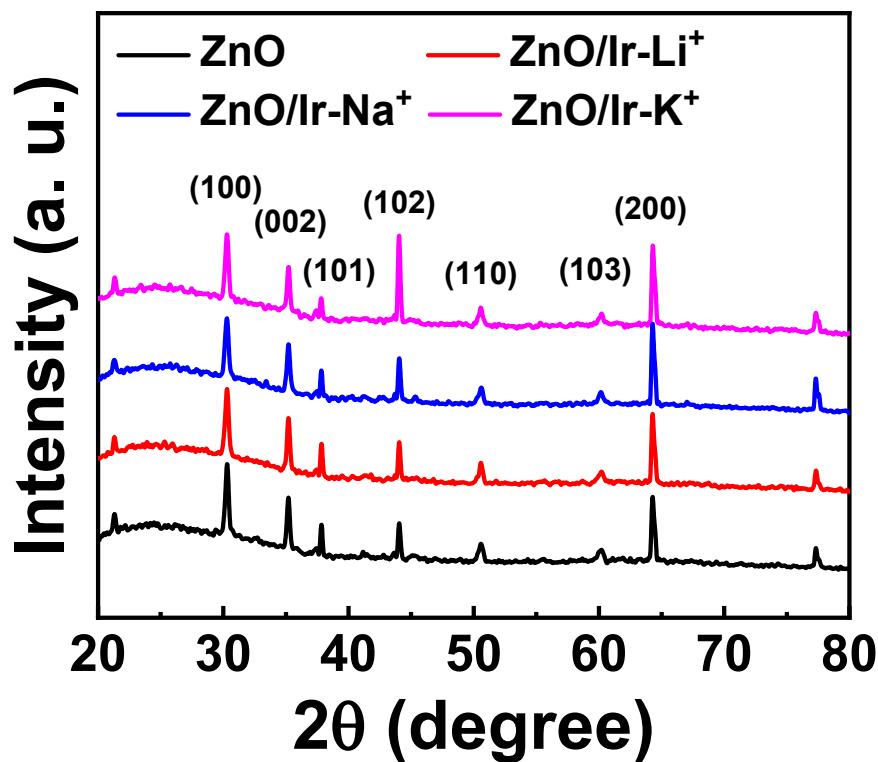


Fig. S13. XRD spectra of ZnO and ZnO/Ir(III) complex films.

XRD spectra show the diffraction peaks of 30.3° , 35.2° and 37.8° correspond to the (100), (002) and (101) planes of the ZnO crystal, confirming that formation of the Ir(III) complex layer does not affect to coated ZnO layer.

3. Grazing incidence wide angle X-ray diffraction (GI-WAXD)

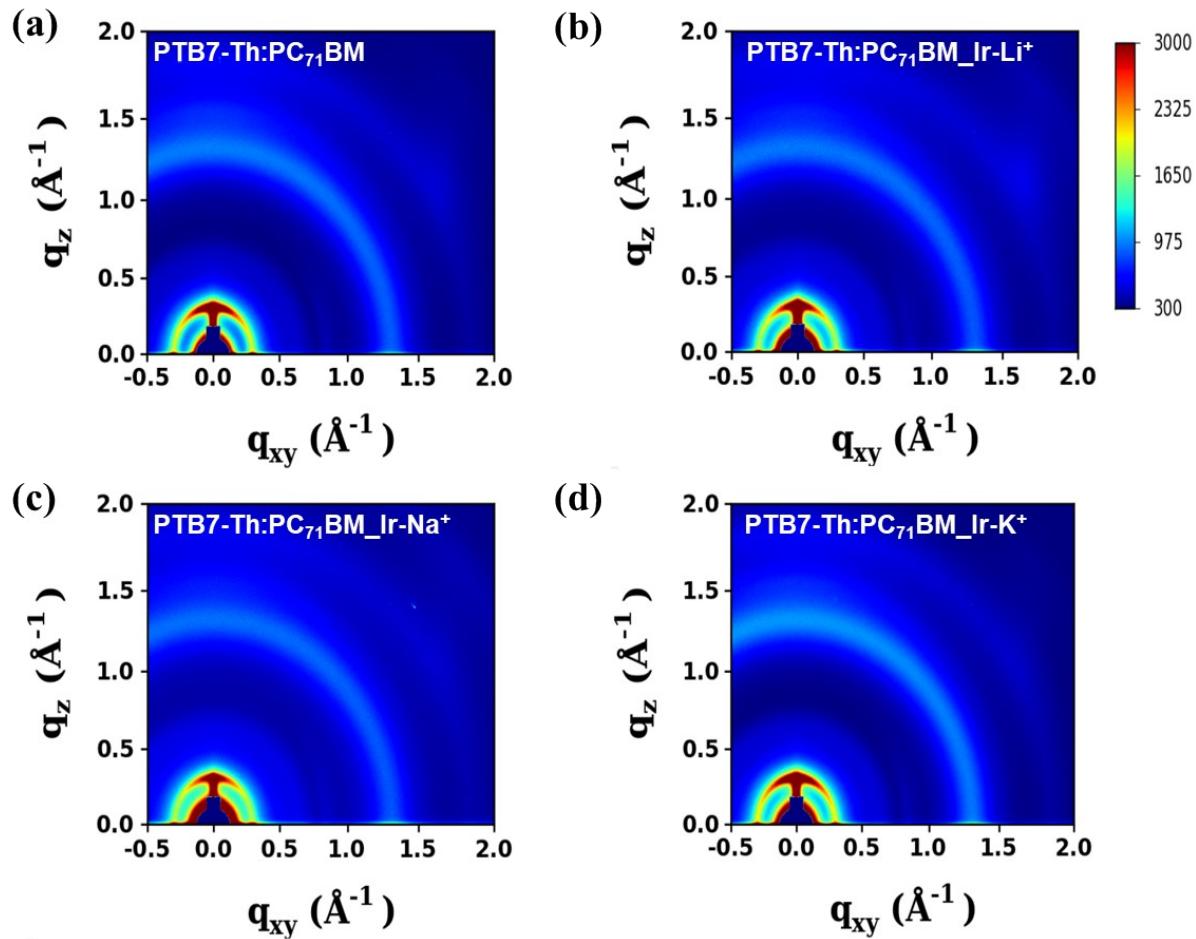


Fig. S14. 2D GI-WAXD images of PTB7-Th:PC₇₁BM films with (a) ZnO layer, (b) ZnO/Ir-Li⁺ layer, (c) ZnO/Ir-Na⁺ layer and (d) ZnO/Ir-K⁺ layer

4. Device performance

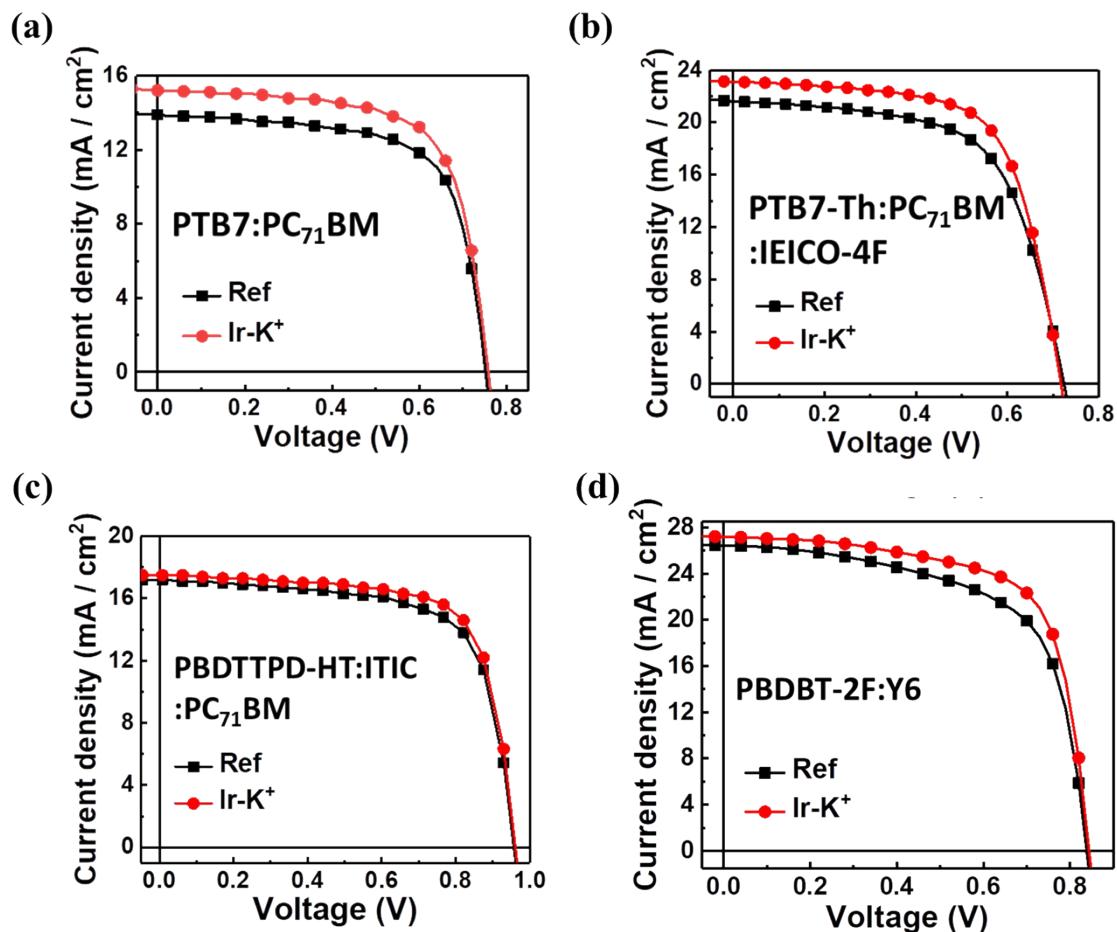


Fig. S15. J-V curves of (a) PTB7:PC₇₁BM blends, (b) PTB7-Th:PC₇₁BM:IEICO-4F blends, (c) PBDTTPD-HT:ITIC:PC₇₁BM blends and (d) PBDBT-2F:Y6 blends device with ZnO/Ir-K⁺ layer

5. Incident photon to current (IPCE) characteristics

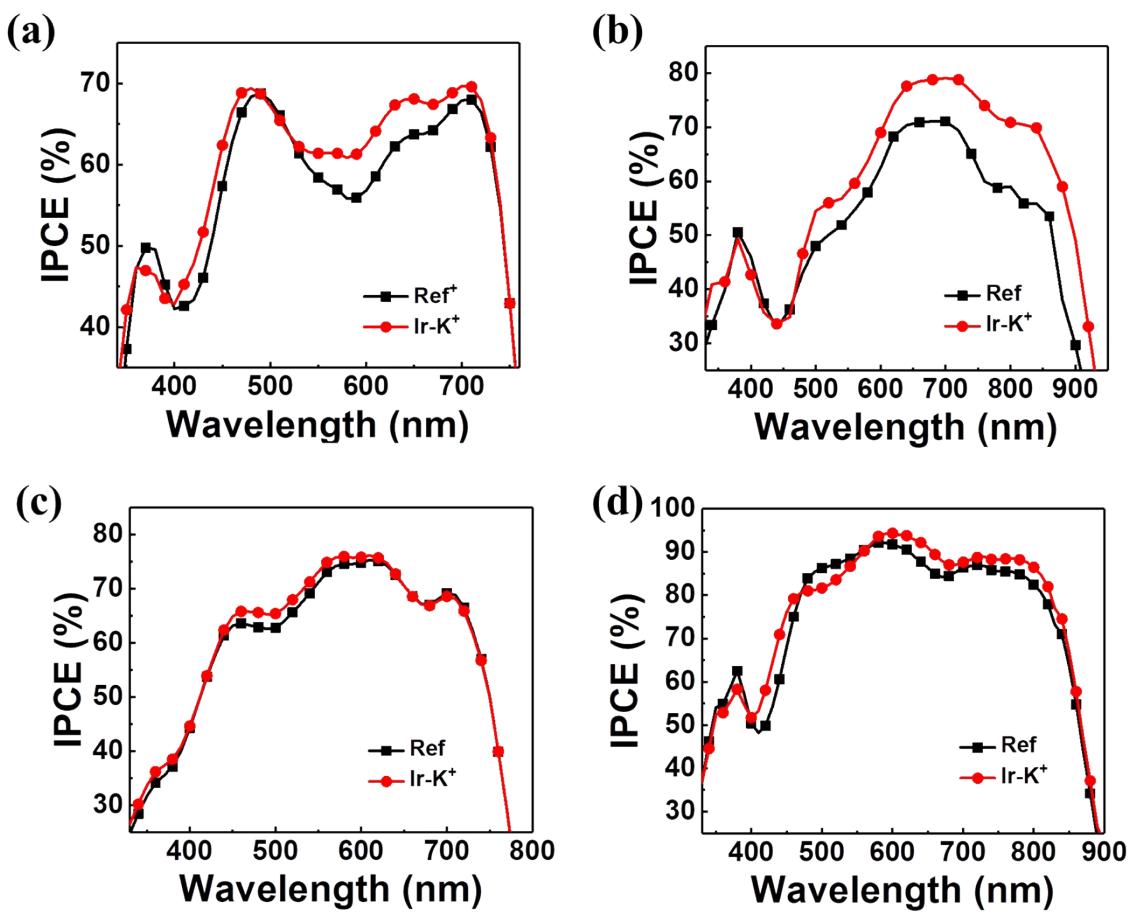


Fig. S16. IPCE characteristics of (a) PTB7:PC₇₁BM blends, (b) PTB7-Th:PC₇₁BM:IEICO-4F blends, (c) PBDTTPD-HT:ITIC:PC₇₁BM blends and (d) PBDBT-2F:Y6 blends devices.

.6. Stability test (Under UV illumination)

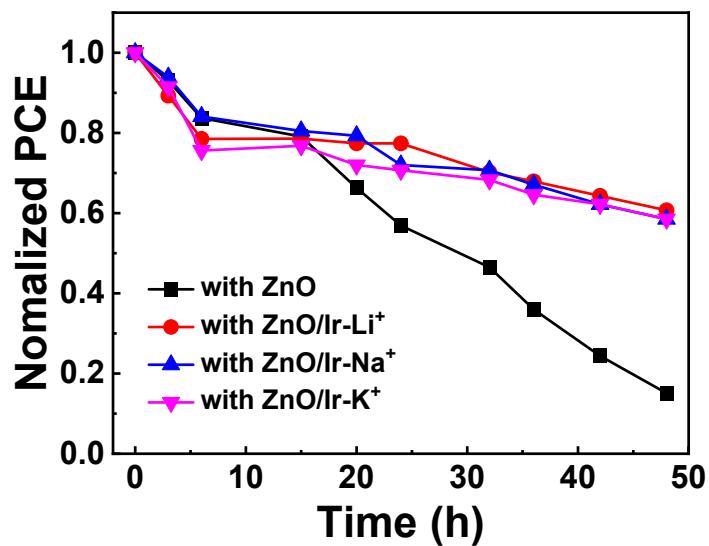


Fig. S17. Stability test under UV illumination with structure of ITO/ZnO/Ir(III) complexes:PEO/PTB7-Th:PC₇₁BM/MoO₃/Ag.

7. X-ray photoelectron spectroscopy (XPS) depth profile

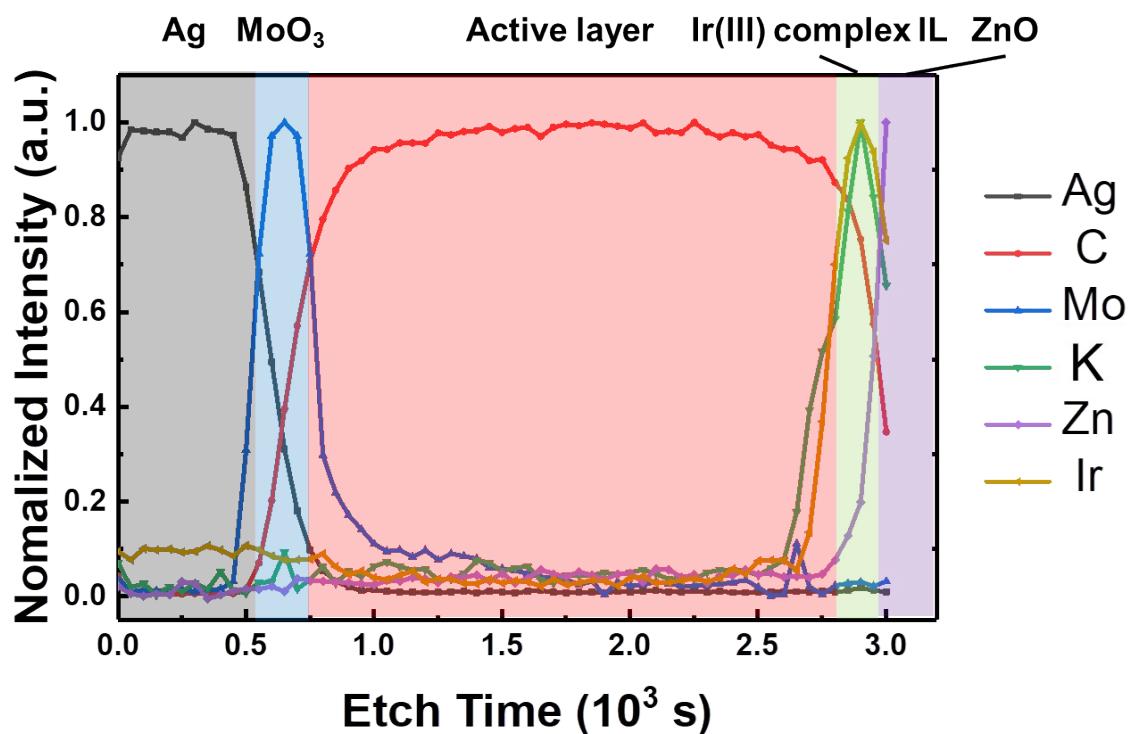


Fig. S18. XPS depth profile of aged device with structure of ITO/ZnO/Ir-K⁺:PEO/PTB7-Th:PC₇₁BM/MoO₃/Ag under AM 1.5 G irradiation (108 h).

8. UV-aged GI-WAXD images

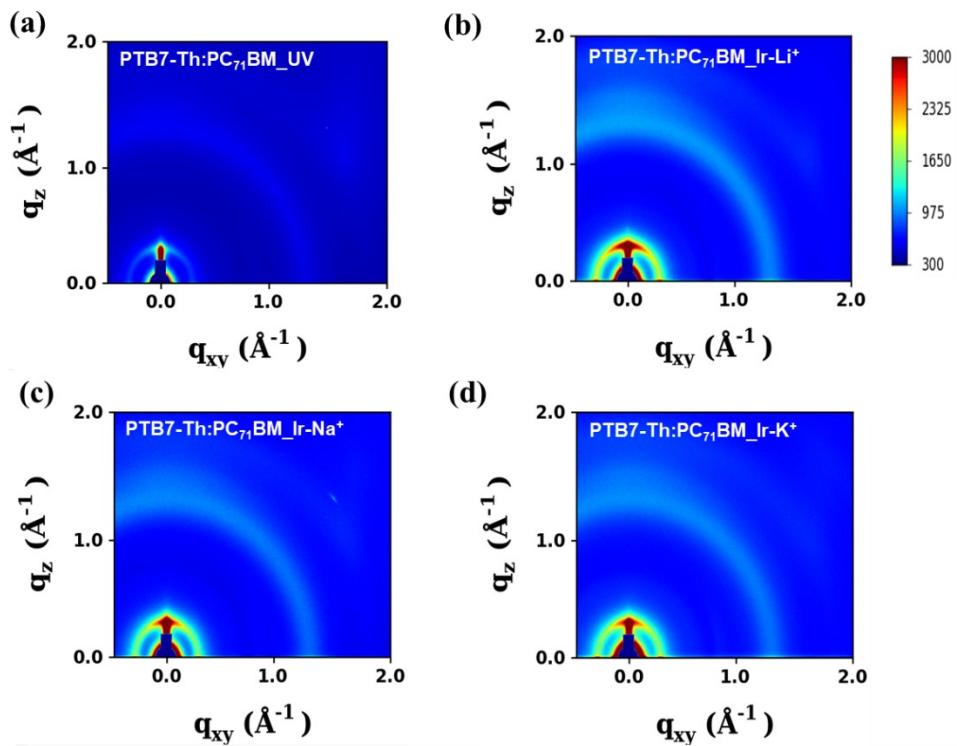


Fig. S19. 2D GI-WAXD images of UV aged PTB7-Th:PC₇₁BM blend films (a) without Ir(III) complex-ILs, (b) with Ir-Li⁺ layer, (c) with Ir-Na⁺ layer and (d) with Ir-K⁺ layer. The aged devices and films were aged under UV light in ambient condition for 48 h before testing (Device structure is ITO/ZnO/Ir(III) complex:PEO/PTB7-Th:PC₇₁BM/MoO₃/Ag).

10. Summary tables of properties and performances

Table S1. EDXS data of ITO/ZnO/Ir-Na⁺ films.

Element	Weight %	Atomic %	Net Int.	Error %	K ratio	Z	R	A	F
C	4.42	13.74	10.33	16.37	0.02	1.38	0.84	0.33	1
O	19.46	45.45	54.92	12.33	0.06	1.31	0.86	0.24	1
Zn	20.02	11.44	57.23	10.29	0.12	0.95	1.02	0.63	1
Na	1.80	2.92	8.36	29.86	0.01	1.18	0.9	0.41	1
Si	8.42	11.20	67.17	9.12	0.07	1.18	0.92	0.72	1
In	45.75	14.89	88.46	7.33	0.37	0.81	1.1	1.02	1

Table S2. EDXS data of ITO/ZnO/Ir-K⁺ films.

Element	Weight %	Atomic %	Net Int.	Error %	K ratio	Z	R	A	F
C	4.66	14.63	11.31	19.40	0.02	1.38	0.84	0.32	1
O	19.04	44.82	57.11	11.28	0.06	1.31	0.86	0.24	1
Zn	21.95	12.65	67.62	7.73	0.13	0.95	1.02	0.64	1
Si	9.02	12.10	76.91	7.22	0.08	1.18	0.92	0.72	1
In	43.85	14.39	90.38	6.63	0.36	0.8	1.1	1.02	1
K	1.47	1.42	6.41	30.02	0.02	1.09	0.96	0.95	1

Table S3. Photo-physical properties of Ir(III) complexes^a

Material	$\lambda_{\max, \text{abs}(\pi-\pi^*)}$ [nm]	$\lambda_{\max, \text{abs} (\text{MLCT})}$ [nm]
Ir-Li ⁺	340	455
Ir-Na ⁺	340	455
Ir-K ⁺	340	455

^a Photophysical data were determined at room temperature in 2-MeTHF solution.

Table S4. Summary of the PSCs performance with the inverted structure of ITO/ZnO/Ir(III) complex (Ir-Li⁺, Ir-Na⁺, and Ir-K⁺):PEO/active layer/MoO₃/Ag.^a

Active layer	J_{SC} (mA cm ⁻²)	V_{OC} (V)	FF	PCE _{max} (%)
PTB7:PC ₇₁ BM	13.9 (13.7)	0.75 (0.75)	0.68 (0.66)	7.1 (6.8)
PTB7:PC ₇₁ BM_Ir-K ⁺	15.2 (15.0)	0.76 (0.76)	0.69 (0.68)	8.0 (7.8)
PTB7-Th:PC ₇₁ BM:IEICO-4F	21.6 (21.1)	0.72 (0.72)	0.62 (0.61)	9.8 (9.3)
PTB7-Th:PC ₇₁ BM:IEICO-4F_Ir-K ⁺	23.1 (22.6)	0.72 (0.72)	0.66 (0.64)	11.0 (10.7)
PBDTTPD-HT:ITIC:PC ₇₁ BM	17.2 (17.2)	0.96 (0.94)	0.69 (0.67)	11.4 (10.9)
PBDTTPD-HT:ITIC:PC ₇₁ BM_Ir-K ⁺	17.5 (17.2)	0.96 (0.94)	0.72 (0.70)	12.1 (11.4)
PBDBT-2F:Y6	26.4 (25.3)	0.84 (0.82)	0.63 (0.68)	14.0 (14.0)
PBDBT-2F:Y6_Ir-K ⁺	27.2 (25.7)	0.84 (0.83)	0.68 (0.71)	15.6 (14.9)

^aThe values in brackets are average values of six replicate devices.